

# Li Xinyu

## List of Publications by Year in descending order

Source: <https://exaly.com/author-pdf/1941184/publications.pdf>

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#	ARTICLE	IF	CITATIONS
1	Degradation of Radiation-Hardened Vertical Double-Diffused Metal-Oxide-Semiconductor Field-Effect Transistor During Gamma Ray Irradiation Performed After Heavy Ion Striking. IEEE Electron Device Letters, 2020, 41, 216-219.	3.9	15
2	Gate Oxide Damage of SiC MOSFETs Induced by Heavy-Ion Strike. IEEE Transactions on Electron Devices, 2021, 68, 4010-4015.	3.0	11
3	A Novel Split-Gate-Trench MOSFET Integrated With Normal Gate and Built-In Channel Diode. IEEE Journal of the Electron Devices Society, 2021, 9, 839-845.	2.1	4
4	Degradation in super-junction MOSFET under successive exposure of heavy ion strike and gamma ray irradiation. Microelectronics Reliability, 2022, 132, 114529.	1.7	2